

## Replacement Sheet

Attorney Docket No. 24061.148

UTILIZE DEEP TRENCH STRUCTURE TO PREVENT LDMOS FROM PARASITIC TURNING-ON CHANNELS

SHEET 1 OF 3

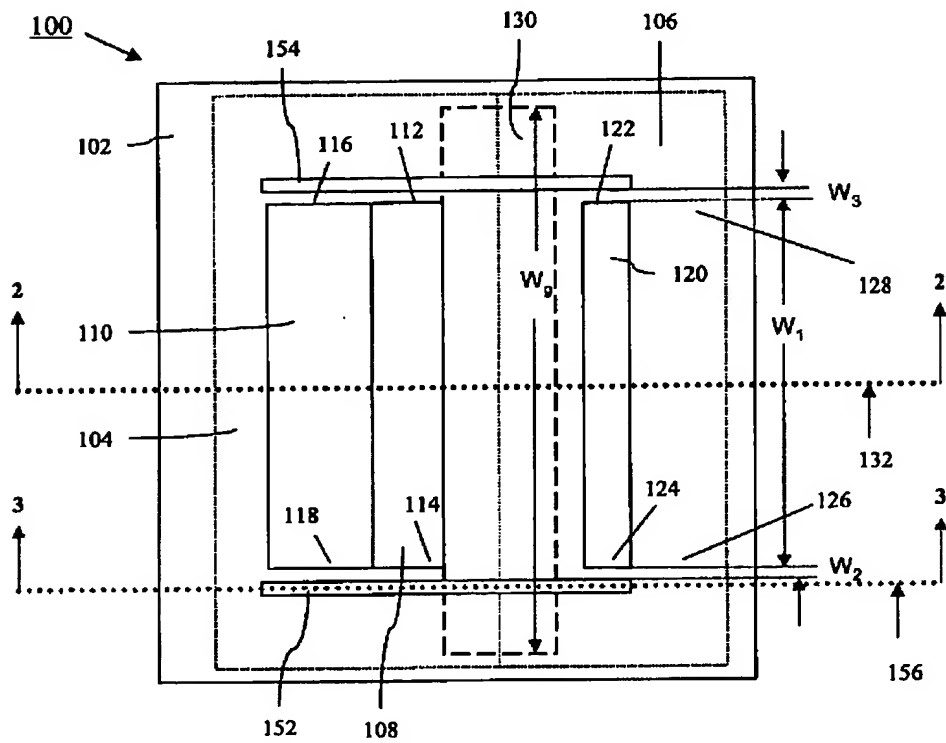


Fig. 1

## Replacement Sheet

Attorney Docket No. 24061.148

UTILIZE DEEP TRENCH STRUCTURE TO PREVENT LDMOS FROM PARASITIC TURNING-ON CHANNELS

SHEET 2 OF 3

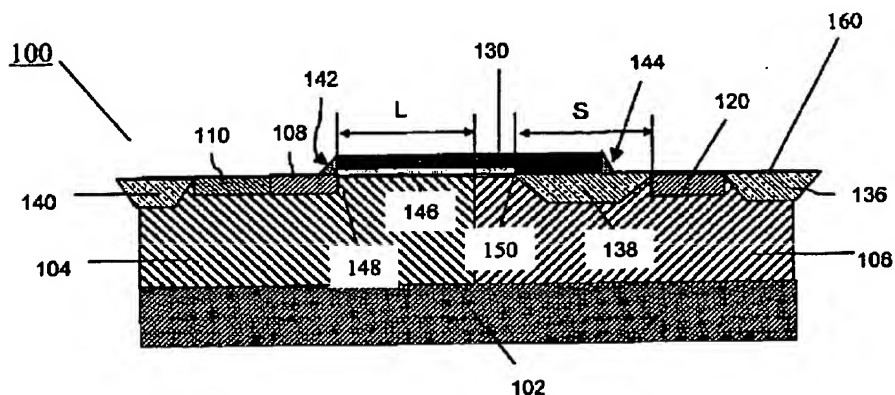


Fig. 2

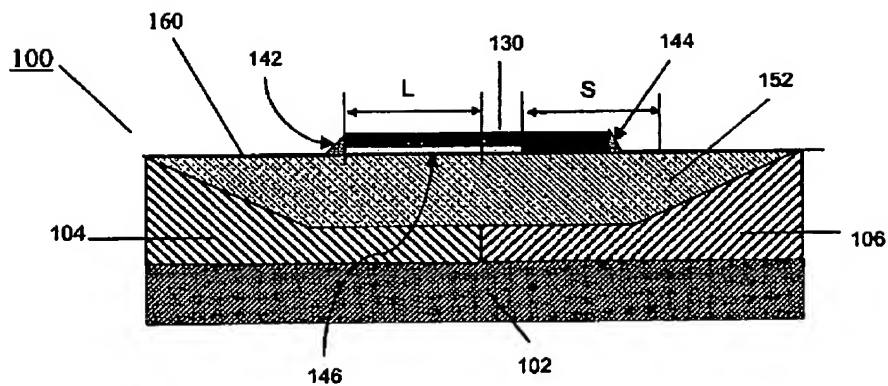


Fig. 3

## Replacement Sheet

Attorney Docket No. 24061.148

UTILIZE DEEP TRENCH STRUCTURE TO PREVENT LDMOS FROM PARASITIC TURNING-ON CHANNELS

SHEET 3 OF 3

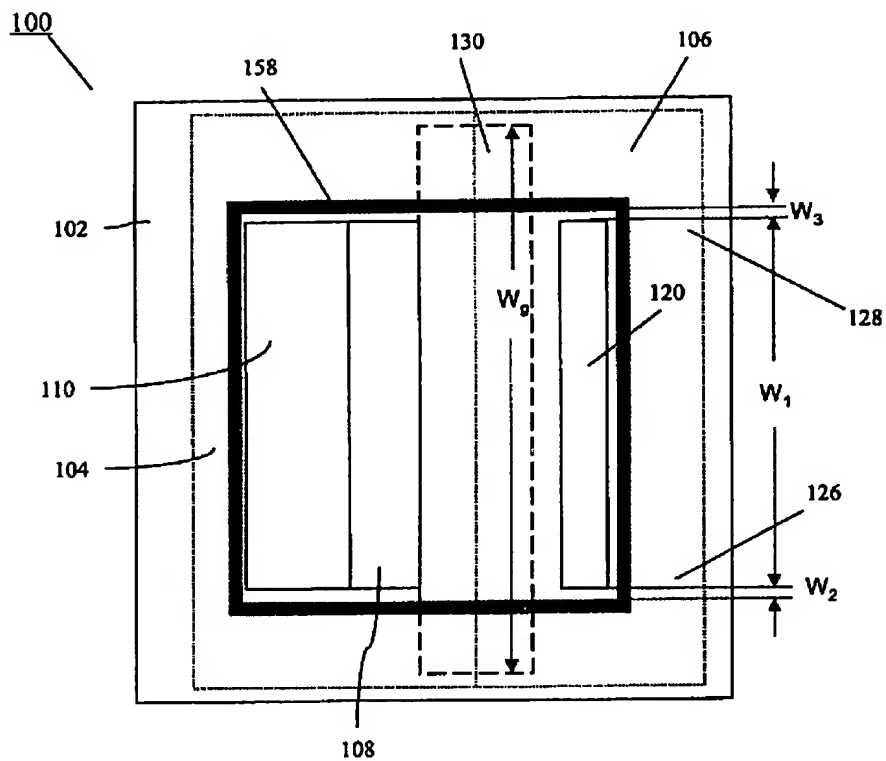


Fig. 4